

Sample &

Buv



LME49720

BODY SIZE (NOM)

9.08mm × 9.08mm

4.90mm × 3.91mm

9.81mm × 6.35mm

SNAS393D-MARCH 2007-REVISED NOVEMBER 2016

Support &

The LME49720 device is part of the ultra-low

distortion, low noise, high slew rate operational

amplifier series optimized and fully specified for high

performance, high fidelity applications. Combining advanced leading-edge process technology with

state-of-the-art circuit design, the LME49720 audio

operational amplifiers deliver superior audio signal

amplification for outstanding audio performance. The

LME49720 combines extremely low voltage noise density (2.7nV/vHz) with vanishingly low THD+N

(0.00003%) to easily satisfy the most demanding

Device Information⁽¹⁾

PACKAGE

(1) For all available packages, see the orderable addendum at

TO-99 (8)

SOIC (8)

PDIP (8)

Community

20

Tools &

3 Description

audio applications.

PART NUMBER

the end of the data sheet.

I ME49720

Software

LME49720 Dual High Performance, High Fidelity Audio Operational Amplifier

Technical

Documents

Features 1

- Easily Drives 600Ω Loads
- Optimized for Superior Audio Signal Fidelity
- **Output Short Circuit Protection**
- PSRR and CMRR Exceed 120dB (typ)
- SOIC, PDIP, TO-99 Metal Can Packages
- **Key Specifications**
 - Power Supply Voltage Range: ±2.5 to ±17V
 - THD+N ($A_V = 1$, $V_{OUT} = 3V_{RMS}$, $f_{IN} = 1$ kHz):
 - $-R_1 = 2k\Omega$: 0.00003% (typ)
 - R_L = 600 Ω : 0.00003% (typ)
 - Input Noise Density: $2.7 \text{nV}/\sqrt{\text{Hz}}$ (typ)
 - Slew Rate: ±20V/µs (typ)
 - Gain Bandwidth Product: 55MHz (typ)
 - Open Loop Gain ($R_1 = 600\Omega$): 140dB (typ)
 - Input Bias Current: 10nA (typ)
 - Input Offset Voltage: 0.1mV (typ)
 - DC Gain Linearity Error: 0.000009%

2 Applications

- Ultra High Quality Audio Amplification
- **High Fidelity Preamplifiers**
- **High Fidelity Multimedia**
- State of the Art Phono Pre Amps
- High Performance Professional Audio
- High Fidelity Equalization and Crossover Networks
- **High Performance Line Drivers**
- **High Performance Line Receivers**
- **High Fidelity Active Filters**

3320Ω 150Ω 3320Ω 150Ω ₩₩∽ WM ww WW 26.1 kΩ 909Ω ww LME49720 LME49720 3.83 kΩ OUTPUT 22 n F//4.7 nF//500 pF 10 pF + 100Ω INPUT 47 k(47 nF//33 nF

Passively Equalized RIAA Phono Preamplifier

Note: 1% metal film resistors, 5% polypropylene capacitors

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (April 2013) to Revision D

•	Added Device Information table, ESD Ratings table, Feature Description section, Device Functional Modes, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical,	
	Packaging, and Orderable Information section.	. 1
•	Changed R _{eJA} values for D and P packages from 145 °C/W to 107.9 °C/W (D) and from 102 °C/W to 72.9 °C/W (P)	
	in the Thermal Information table.	. 4

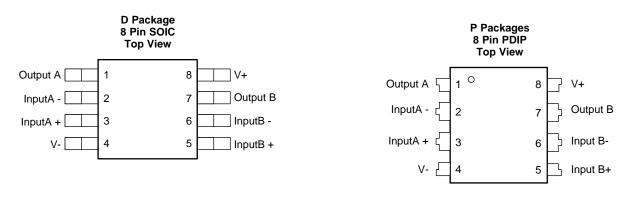
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Page

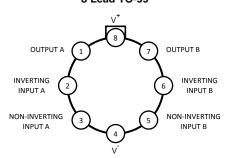
5 Device Comparison Table

Device Number	Amplifier Type	Number of Channel	Output Current (mA)	Input Noise Density (nV/rtHz)	THD+N (%)
LME49710	Audio Operational	1	37	2.5	0.00003
LME49720	Audio Operational	2	26	2.7	0.00003
LME49721	Audio Operational	2	100	4	0.0002
LME49723	Audio Operational	2	25	3.2	0.0002

6 Pin Configuration and Functions



LMC Package 8 Lead TO-99



Pin Functions

	P	IN		I/O	DESCRIPTION
NAME	SOIC	PDIP	TO-99		
V+	8	8	8	-	Positive supply voltage
V-	4	4	4	-	Negative supply voltage
InputA-	2	2	2	I	Negative audio input
InputA+	3	3	3	I	Positive audio input
Output A	1	1	1	0	Audio output A
InputB-	6	6	6	I	Negative audio input
InputB+	5	5	5	I	Positive audio input
Output B	7	7	7	0	Audio output B

7 Specifications

7.1 Absolute Maximum Ratings

see (1)(2)(3)

		MIN	MAX	UNIT
Power Supply Voltage	$(V_{S}=V^{+}-V^{-})$		36	V
Input Voltage	(V–) – 0.7V	(V+) + 0.7	V	
Output Short Circuit (4)		Con	tinuous	
Power Dissipation		Interna	lly Limited	
Junction Temperature			150	°C
Temperature Range	$T_{MIN} \le T_A \le T_{MAX}$	-40	85	°C
Supply Voltage Range		±2.5V ≤ V _S ≤ ± 17V		V
Storage Temperature			150	°C

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

(2) Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For enusred specifications and test conditions, see Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

(3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

(4) Amplifier output connected to GND, any number of amplifiers within a package.

7.2 ESD Ratings

				VALUE	UNIT
		Human-body model (HBM) ⁽¹⁾	All pins	2000	
V _(ESD)	Electrostatic discharge	Machine Model (MM), per EIAJ IC-121-	Pins 1, 4, 7 and 8	200	V
		1981 Application and Implementation	Pins 2, 3, 5 and 6	100	

(1) Human body model, 100pF discharged through a $1.5k\Omega$ resistor.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
V+,V-	Supply voltage	±2.5	±17	V
T _A	Operating free-air temperature	-40	85	°C
TJ	Operating junction temperature	-40	150	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾			LME49720		
		D (SOIC)	P (PDIP)	LMC (TO-99) ⁽²⁾	UNIT
		8 PINS	8 PINS	8 PINS	
R_{\thetaJA}	Junction-to-ambient thermal resistance	107.9	72.9	150	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	52	77.2	35	°C/W
R_{\thetaJB}	Junction-to-board thermal resistance	48.3	44.9	-	°C/W
ΨJT	Junction-to-top characterization parameter	8.2	35.7	-	°C/W
Ψјв	Junction-to-board characterization parameter	47.8	49.9	_	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	_	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

(2) Thermal performance of a TO-99 package will depend strongly on mounting condition and there is no standard mounting configuration on a JEDEC PCB for that package type.



7.5 Electrical Characteristics

The following specifications apply for $V_s = \pm 15V$, $R_L = 2k\Omega$, $f_{IN} = 1$ kHz, and $T_A = 25$ °C, unless otherwise specified.

	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
THD+N	Total harmonic distortion + noise	$\begin{array}{l} A_V = 1, V_{OUT} = 3 V_{rms} \\ R_L = 2 k \Omega \\ R_L = 600 \Omega \end{array}$		0.00003 0.00003	0.00009	%
IMD	Intermodulation distortion	A _V = 1, V _{OUT} = 3V _{RMS} Two-tone, 60Hz & 7kHz 4:1		0.00005		%
GBWP	Gain bandwidth product		45	55		MHz
SR	Slew rate		±15	±20		V/µs
FPBW	Full power bandwidth	$V_{OUT} = 1V_{P.P}, -3dB$ referenced to output magnitude at f = 1kHz		10		MHz
t _s	Settling time	$A_V = -1$, 10V step, $C_L = 100 pF$ 0.1% error range		1.2		μS
	Equivalent input noise voltage	$f_{BW} = 20Hz$ to $20kHz$		0.34	0.65	μV_{RMS}
e _n	Equivalent input noise density	f = 1kHz f = 10Hz		2.7 6.4	4.7	nV / √Hz
i _n	Current noise density	f = 1kHz f = 10Hz		1.6 3.1		pA / √Hz
V _{OS}	Offset voltage			±0.1	±0.7	mV
∆V _{OS} /∆Te mp	Average input offset voltage drift vs temperature	$-40^{\circ}C \le T_{A} \le 85^{\circ}C$		0.2		μV/°C
PSRR	Average input offset voltage shift vs power supply voltage	$\Delta V_{\rm S}$ = 20V ⁽³⁾	110	120		dB
ISO _{CH-CH}	Channel-to-Channel isolation	$f_{IN} = 1 \text{kHz}$ $f_{IN} = 20 \text{kHz}$		118 112		dB
I _B	Input bias current	$V_{CM} = 0V$		10	72	nA
∆I _{OS} /∆Te mp	Input bias current drift vs temperature	–40°C ≤ T _A ≤ 85°C		0.1		nA/°C
l _{os}	Input offset current	$V_{CM} = 0V$		11	65	nA
V _{IN-CM}	Common-Mode input voltage range		(V+) – 2.0 (V-) + 2.0	+14.1 –13.9		V
CMRR	Common-Mode rejection	-10V <vcm<10v< td=""><td>110</td><td>120</td><td></td><td>dB</td></vcm<10v<>	110	120		dB
	Differential input impedance			30		kΩ
Z _{IN}	Common mode input impedance	-10V <vcm<10v< td=""><td></td><td>1000</td><td></td><td>MΩ</td></vcm<10v<>		1000		MΩ
		$-10V < Vout < 10V, R_{L} = 600\Omega$	125	140		
A _{VOL}	Open loop voltage gain	$-10V$ <vout<10v, r<sub="">L = 2kΩ</vout<10v,>		140		dB
		$-10V$ <vout<10v, r<sub="">L = 10kΩ</vout<10v,>		140		
		$R_L = 600\Omega$	±12.5	±13.6		
V _{OUTMAX}	Maximum output voltage swing	$R_L = 2k\Omega$		±14.0		V
		$R_L = 10k\Omega$	±14.1			
I _{OUT}	Output current	$R_L = 600\Omega$, $V_S = \pm 17V$	±23	±26		mA
lout-cc	Instantaneous short circuit current			+53 –42		mA
R _{OUT}	Output impedance	f _{IN} = 10kHz Closed-Loop Open-Loop		0.01 13		Ω
C _{LOAD}	Capacitive load drive overshoot	100pF		16		%
I _S	Total quiescent current	I _{OUT} = 0mA		10	12	mA

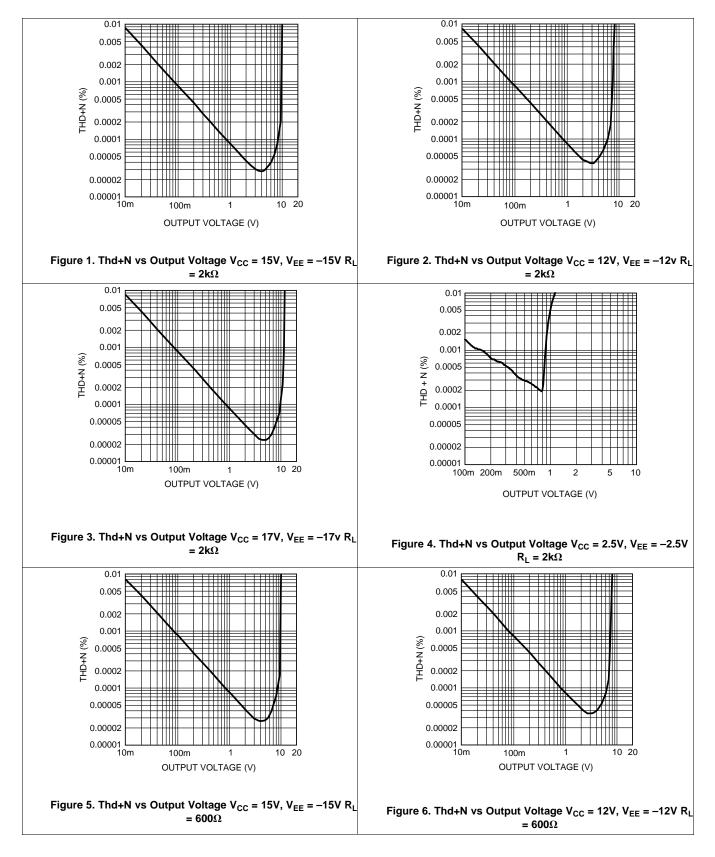
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(2) (3)

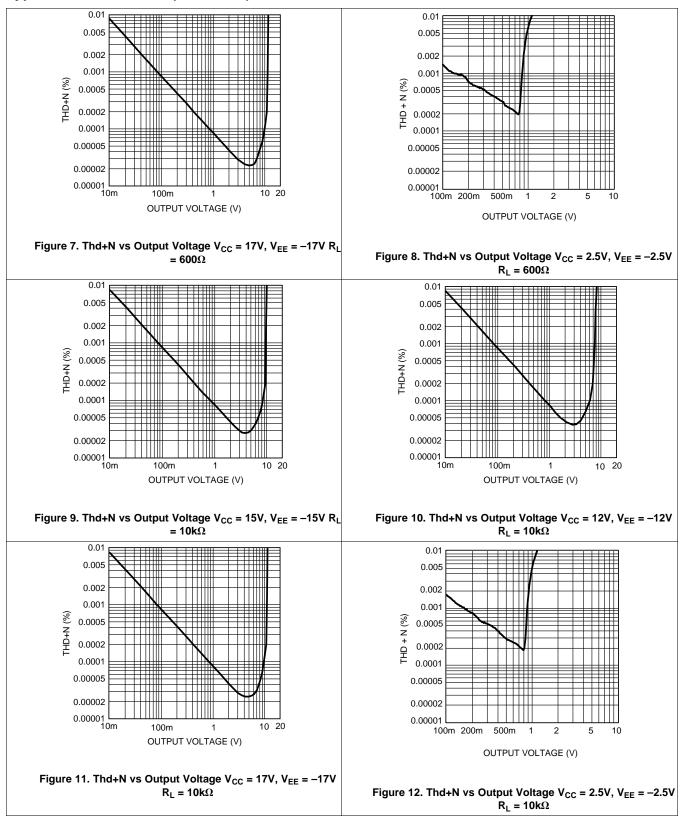
Tested limits are ensured to AOQL (Average Outgoing Quality Level). Typical specifications are specified at +25°C and represent the most likely parametric norm. PSRR is measured as follows: V_{OS} is measured at two supply voltages, ±5V and ±15V. PSRR = | 20log($\Delta V_{OS}/\Delta V_S$) |.



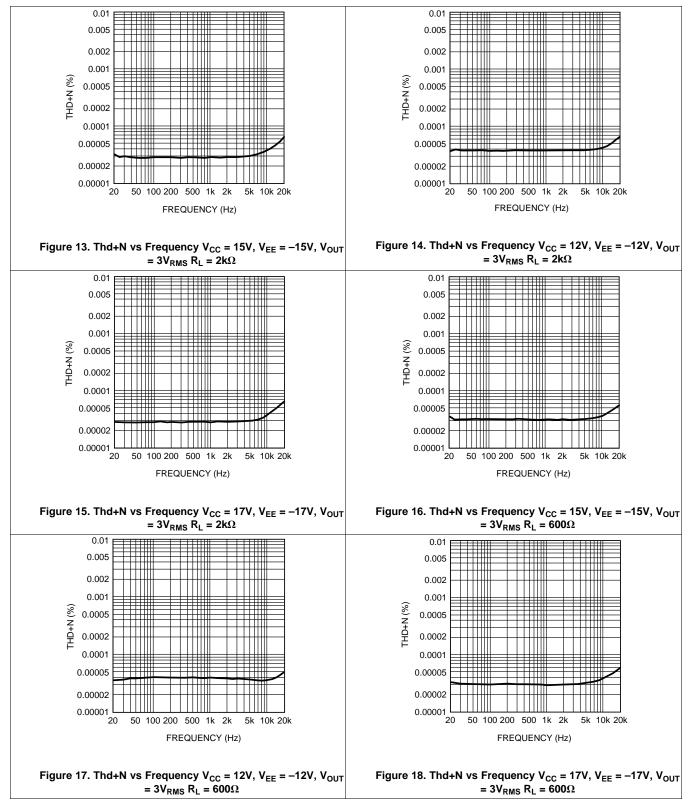
7.6 Typical Characteristics



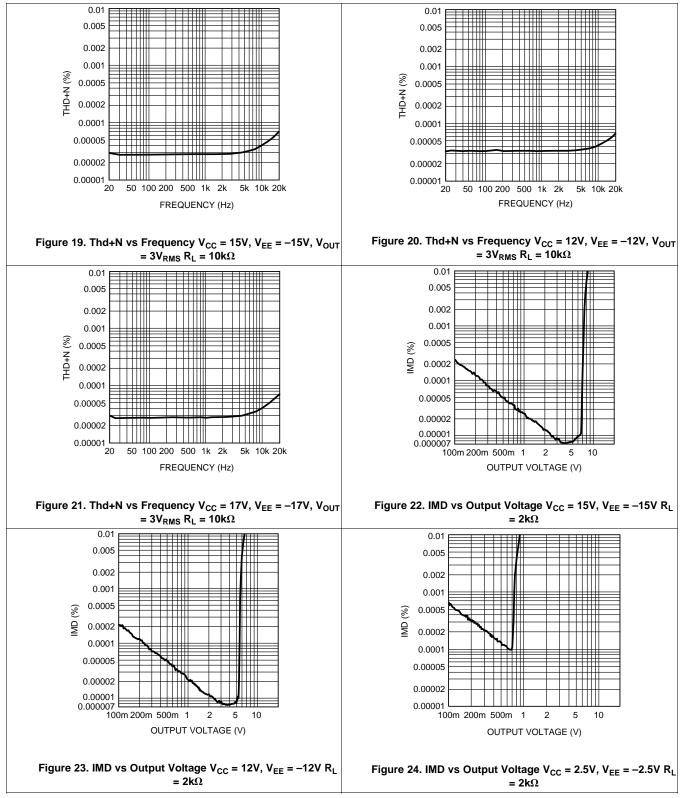




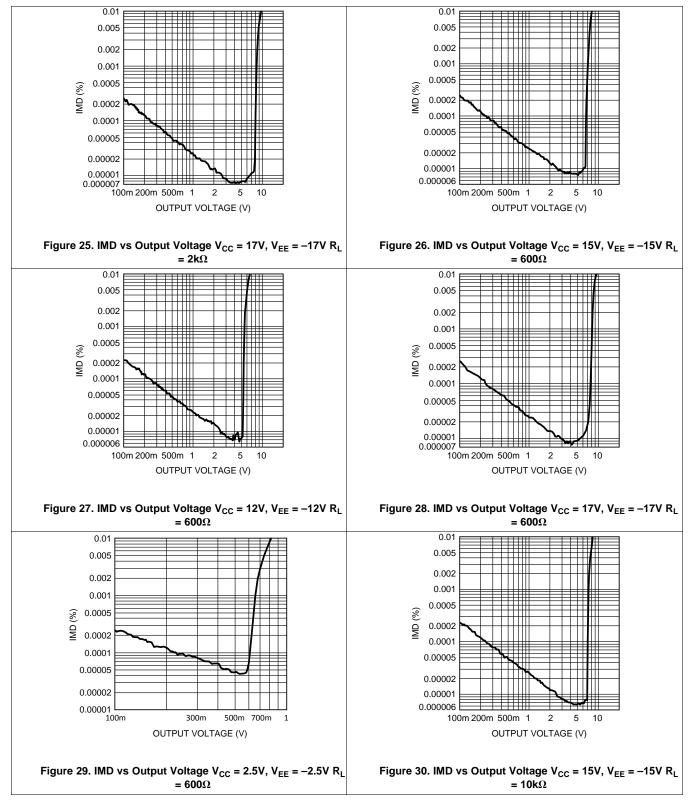




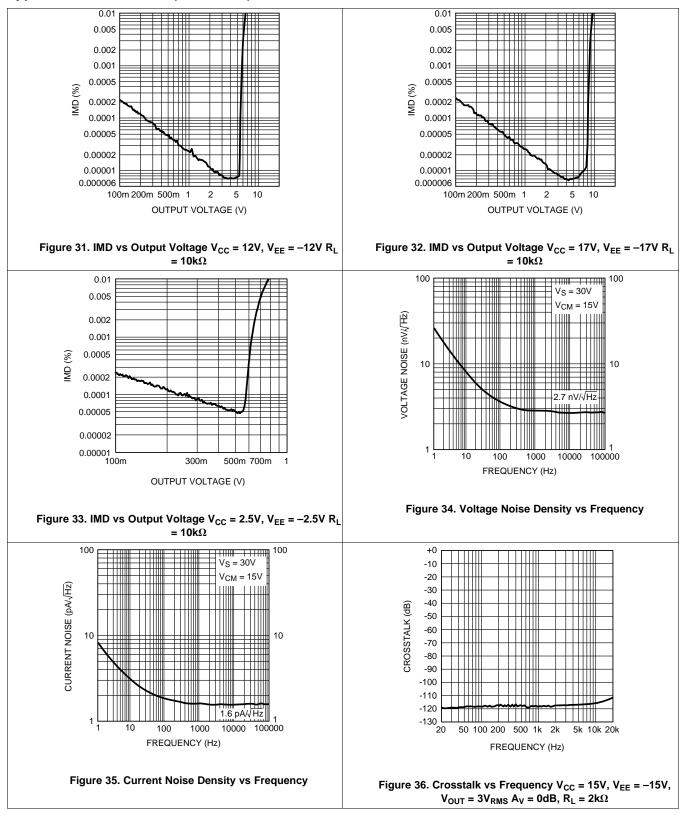




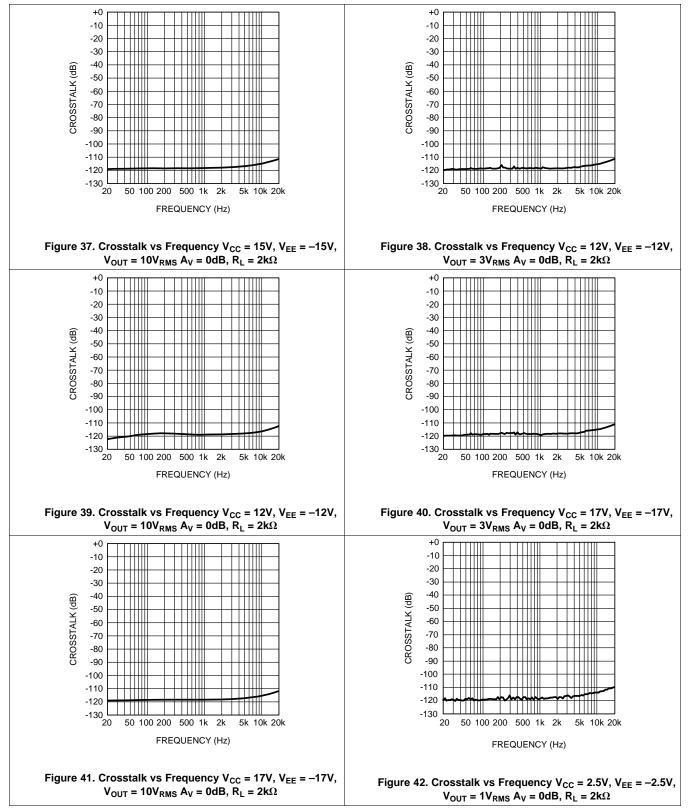




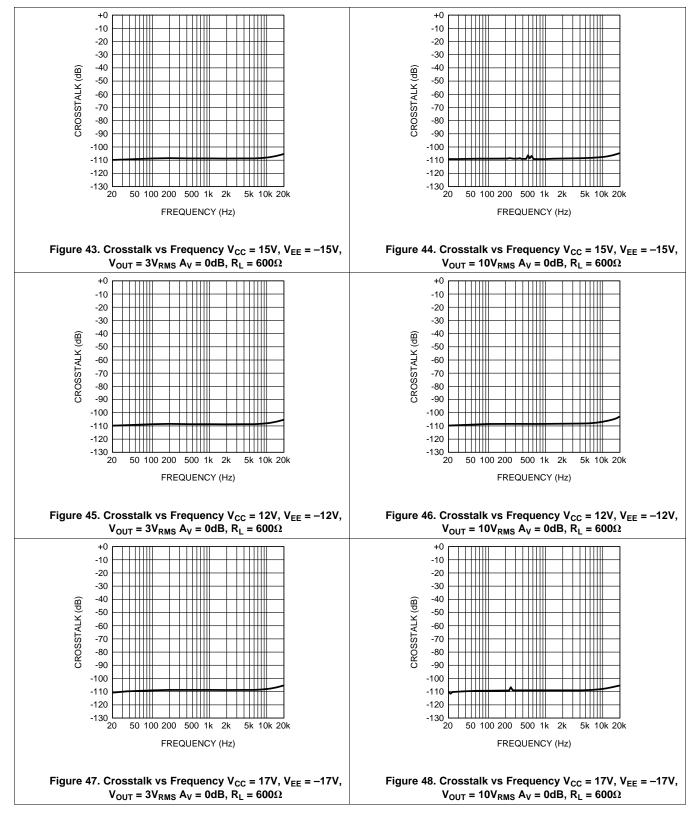




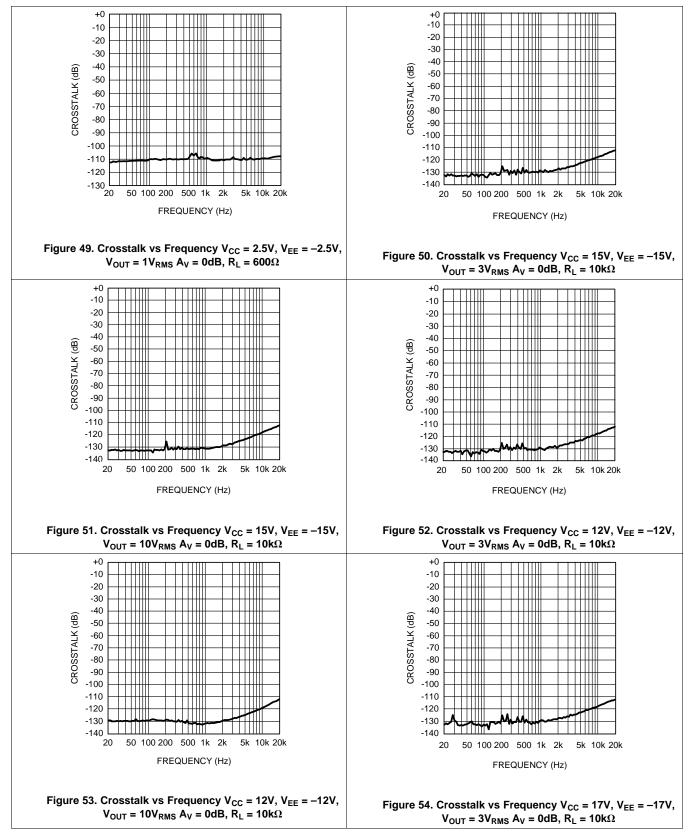




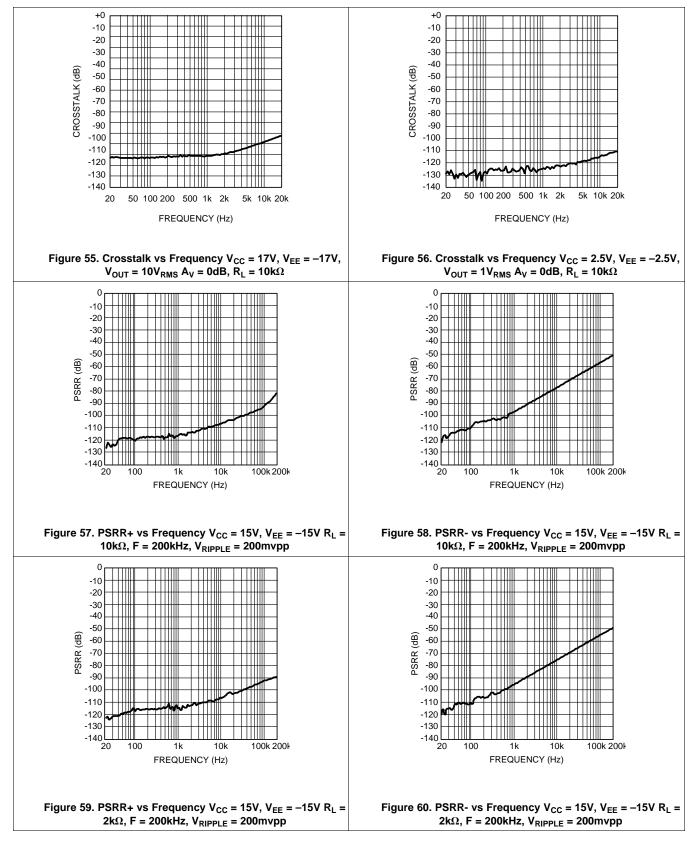






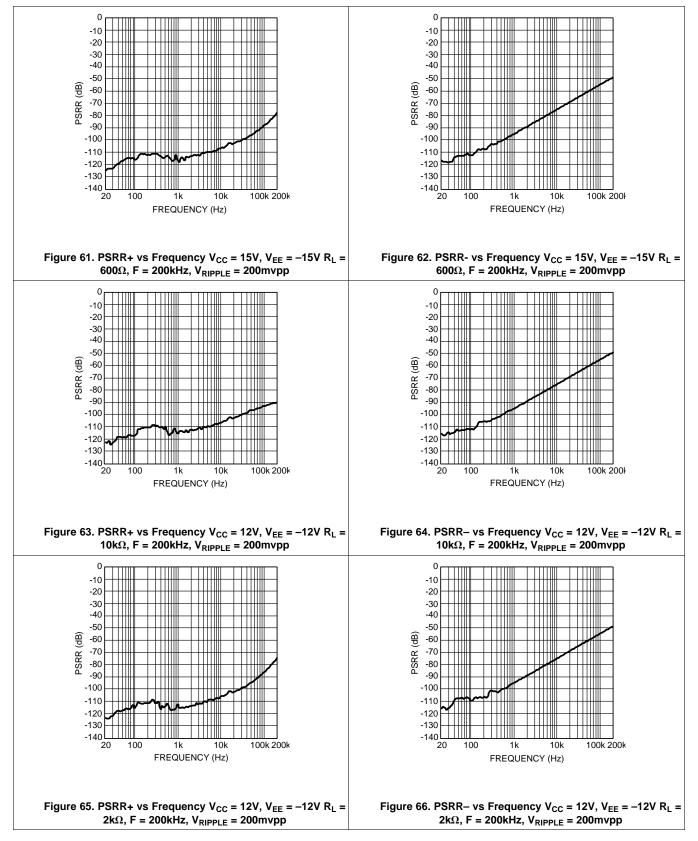




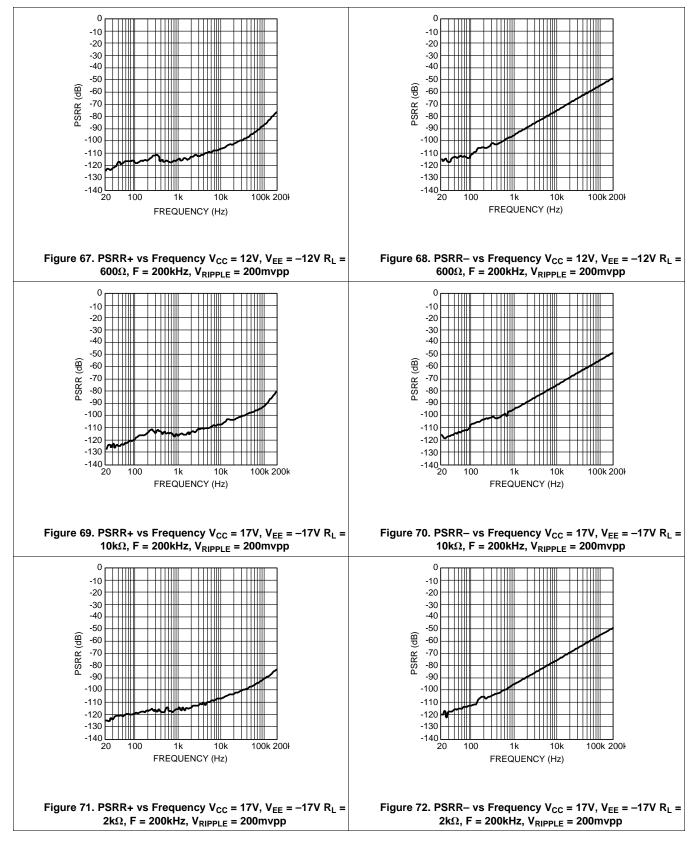


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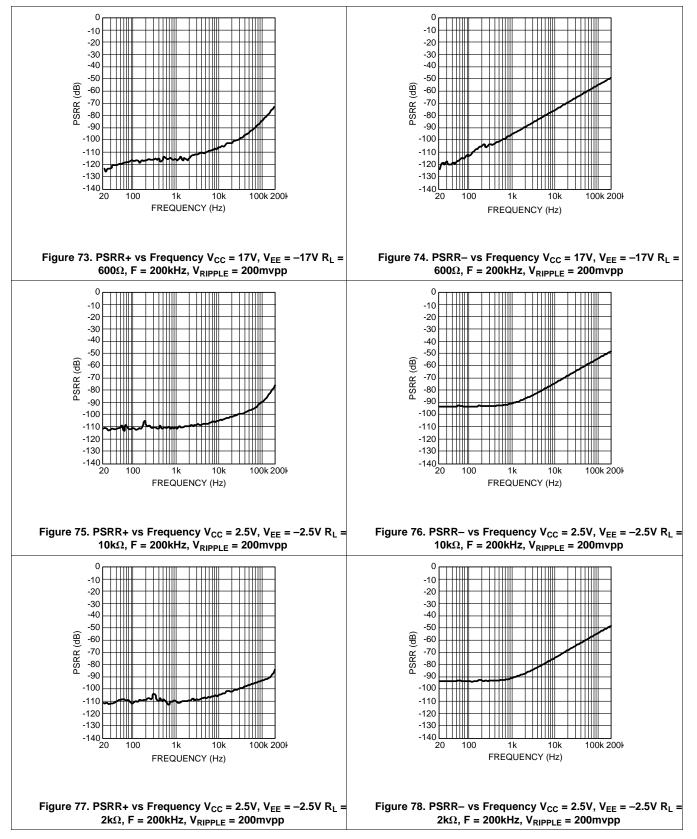




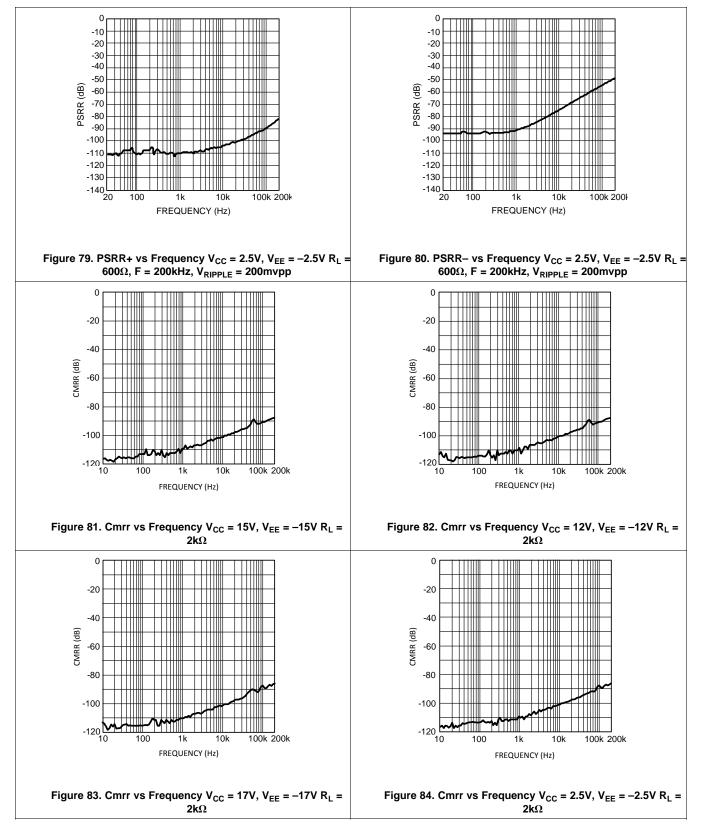


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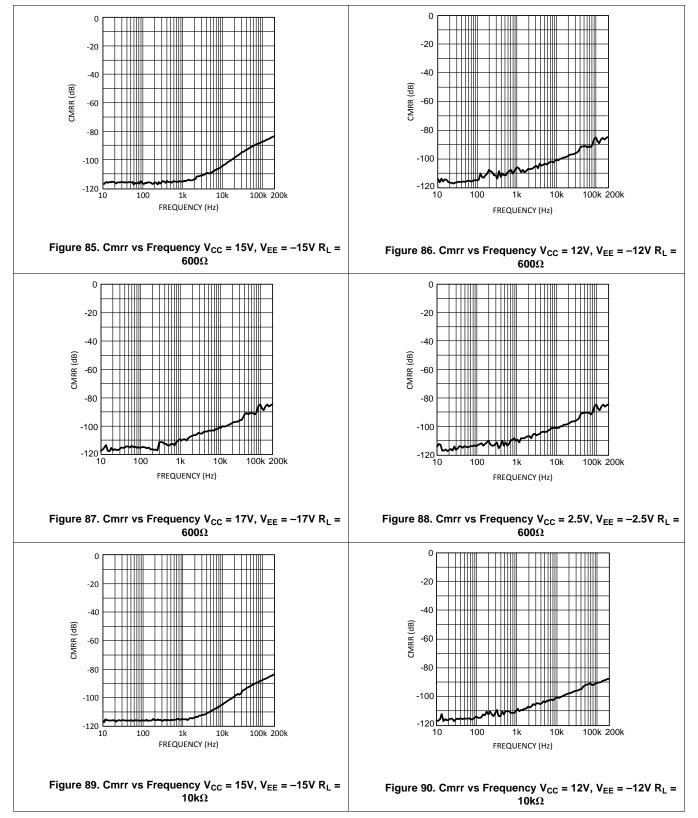
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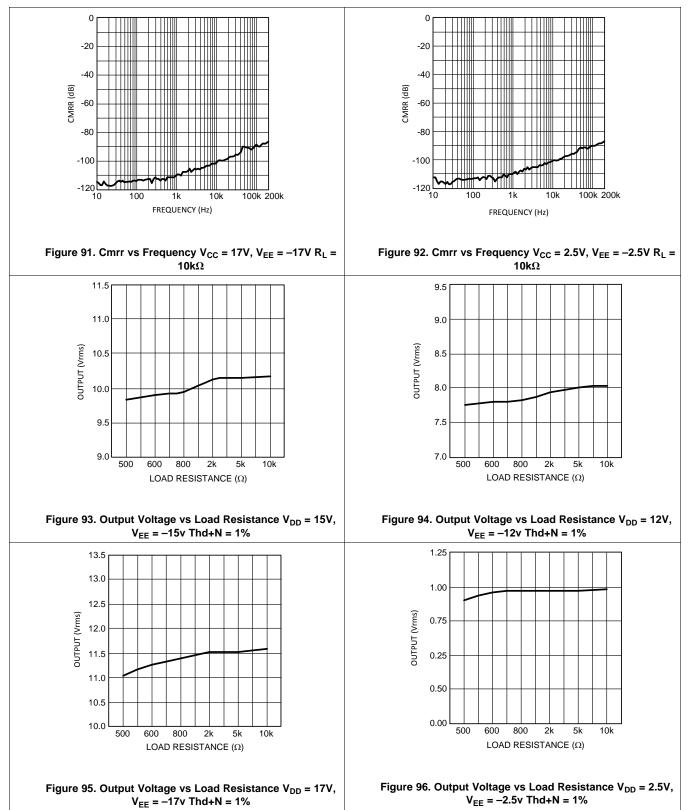




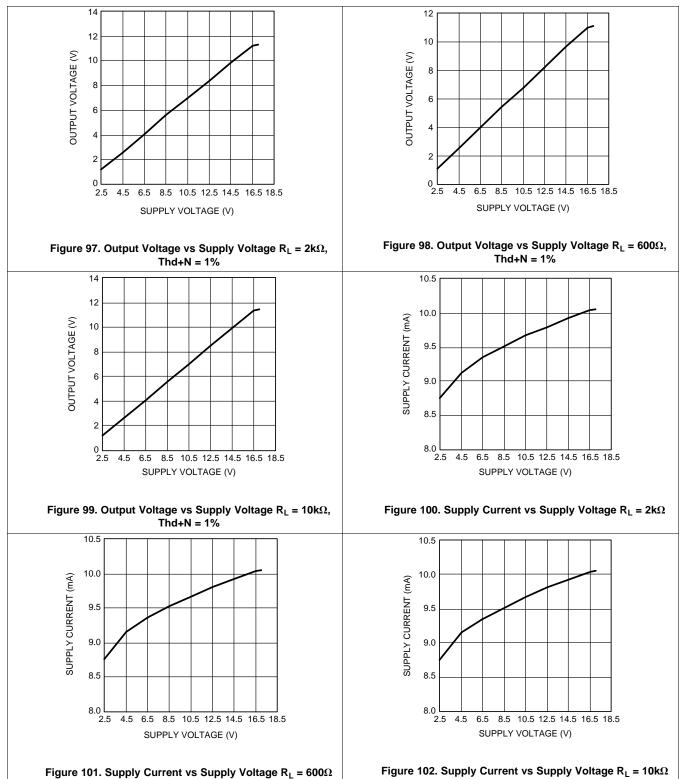




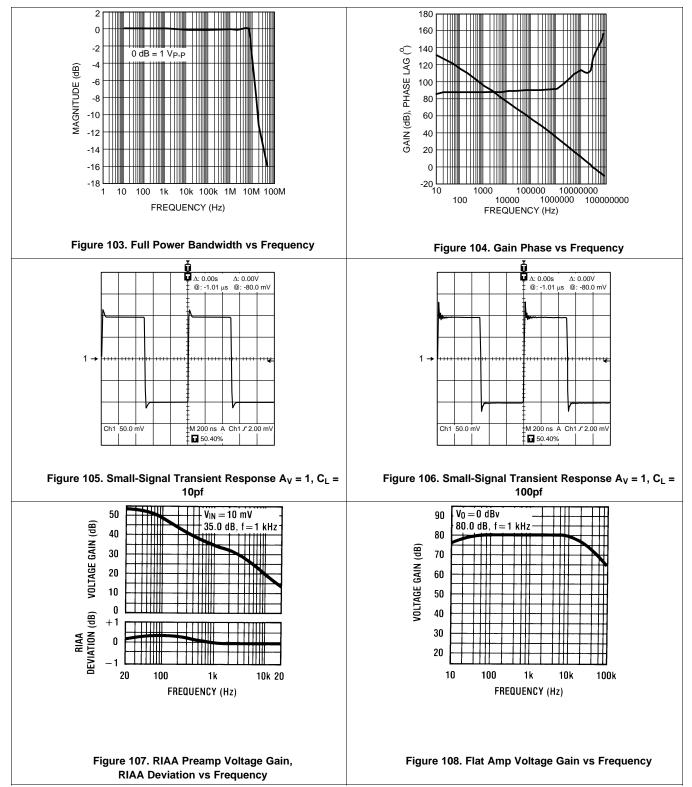














8 Parameter Measurement Information

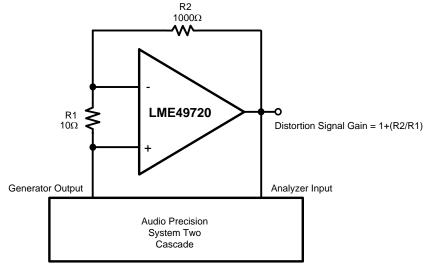
All parameters are measured according to the conditions described in the Specifications section.

8.1 Distortion Measurements

The vanishingly low residual distortion produced by LME49720 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49720's low residual distortion is an input referred internal error. As shown in Figure 109, adding the 10 Ω resistor connected between the amplifier's inverting and non-inverting inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 109.

This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.

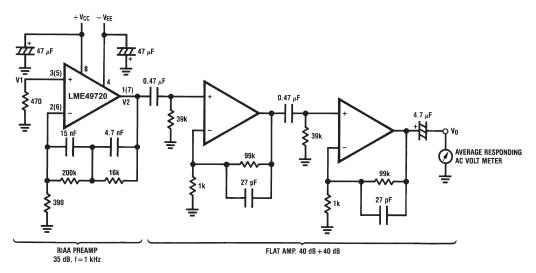


Actual Distortion = AP Value/100

Figure 109. THD+N and IMD Distortion Test Circuit



Distortion Measurements (continued)



Complete shielding is required to prevent induced pick up from external sources. Always check with oscilloscope for power line noise.

Total Gain: 115 dB @F = 1 kHz

Input Referred Noise Voltage: E_n = V0/560,000 (V)

Figure 110. Noise Measurement Circuit

9 Detailed Description

9.1 Overview

The LME49720 audio operational amplifier delivers superior audio signal amplification for outstanding audio performance.

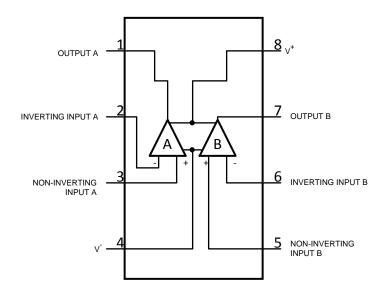
To ensure that the most challenging loads are driven without compromise, the LME49720 has a high slew rate of $\pm 20V/\mu s$ and an output current capability of $\pm 26mA$. Further, dynamic range is maximized by an output stage that drives $2k\Omega$ loads to within 1V of either power supply voltage and to within 1.4V when driving 600Ω loads.

The LME49720's outstanding CMRR (120dB), PSRR (120dB), and V_{OS} (0.1mV) give the amplifier excellent operational amplifier DC performance.

The LME49720 has a wide supply range of $\pm 2.5V$ to $\pm 17V$. Over this supply range the LME49720's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its low input bias current. The LME49720 is unity gain stable. This Audio Operational Amplifier achieves outstanding AC performance while driving complex loads with values as high as 100pF.

The LME49720 is available in 8–lead narrow body SOIC, 8–lead PDIP, and 8–lead TO-99. Demonstration boards are available for each package.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 Capacitive Load

The LME49720 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

9.3.2 Balance Cable Driver

With high peak-to-peak differential output voltage and plenty of low distortion drive current, the LME49720 makes an excellent balanced cable driver. Combining the single-to-differential configuration with a balanced cable driver results in a high performance single-ended input to balanced line driver solution.

Although the LME49720 can drive capacitive loads up to 100pF, cable loads exceeding 100pF can cause instability. For such applications, series resistors are needed on the outputs before the capacitive load.



This device does not have operation mode.

10 Application and Implementation

NOTE

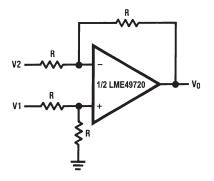
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

These typical connection diagrams highlight the required external components and system level connections for proper operation of the device. Any design variation can be supported by TI through schematic and layout reviews. Visit e2e.ti.com for design assistance and join the audio amplifier discussion forum for additional information

10.2 Typical Applications

10.2.1 Single Ended Converter



 $V_0 = V1 - V2$



10.2.1.1 Design Requirements

For this design example, use the parameters listed in Table 1.

Table 1. Design Parameter	Design Paramete	ers
---------------------------	-----------------	-----

DESIGN PARAMETER	EXAMPLE VALUE
Power Supply	±15
Speaker	2 ΚΩ

LME49720

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10.2.1.2 Detailed Design Procedure

10.2.1.2.1 Surface Mount Capacitors

Temperature and applied DC voltage influence the actual capacitance of high-K materials. Table 2 shows the relationship between the different types of high-K materials and their associated tolerances, temperature coefficients, and temperature ranges. Notice that a capacitor made with X5R material can lose up to 15% of its capacitance within its working temperature range.

Select high-K ceramic capacitors according to the following rules:

- 1. Use capacitors made of materials with temperature coefficients of X5R, X7R, or better.
- 2. Use capacitors with DC voltage ratings of at least twice the application voltage.
- 3. Choose a capacitance value at least twice the nominal value calculated for the application.

Multiply the nominal value by a factor of 2 for safety. If a 10-µF capacitor is required, use 20µF.

The preceding rules and recommendations apply to capacitors used in connection with this device. The LME49720 cannot meet its performance specifications if the rules and recommendations are not followed.

Table 2. Typical Tolerance and Temperature Coefficient of Capacitance by Material

Material	COG/NPO	X7R	X5R
Typical Tolerance	±5%	±10%	80/20%
Temperature	±30ppm	±15%	22/-82%
Temperature Range, ºC	-55/125°C	-55/125⁰C	–30/85 °C

10.2.1.3 Application Curves

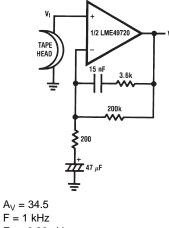
For application curves, see the figures listed in Table 3.

Table 3. Table of Graphs

DESCRIPTION	FIGURE NUMBER
THD+N vs Output Power	See Figure 1
THD+N vs Frequency	See Figure 13
Crosstalk vs Frequency	See Figure 36
PSRR vs Frequency	See Figure 58

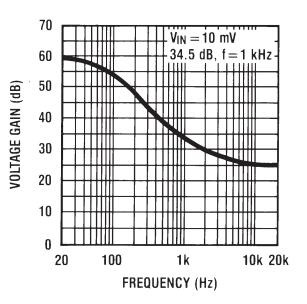


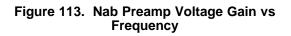
10.2.2 Other Applications

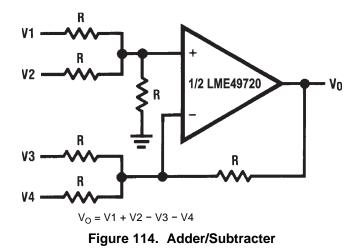












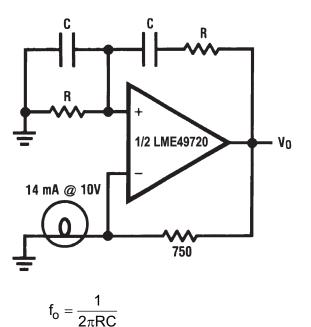
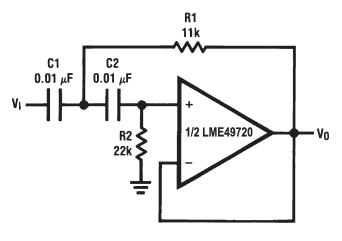


Figure 115. Sine Wave Oscillator



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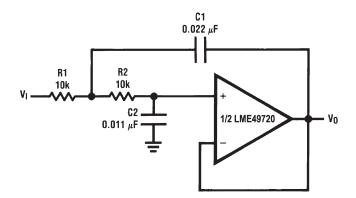


$$if C1 = C2 = C$$
$$R1 = \frac{\sqrt{2}}{2\omega_o C}$$

$$R2 = 2 \times R1$$

Illustration is $f_0 = 1 \text{ kHz}$





if R1 = R2 = R

$$C1 = \frac{\sqrt{2}}{\omega_0 R}$$

$$C2 = \frac{C1}{2}$$
Illustration is f₀ = 1 kHz

Figure 117. Second Order Low Pass Filter (Butterworth)

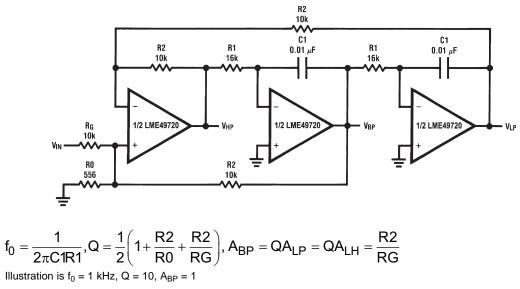
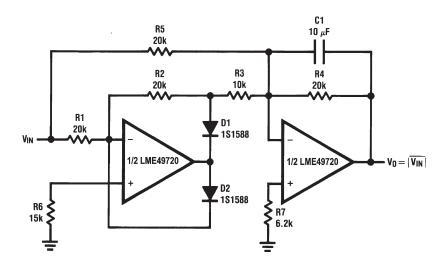


Figure 118. State Variable Filter







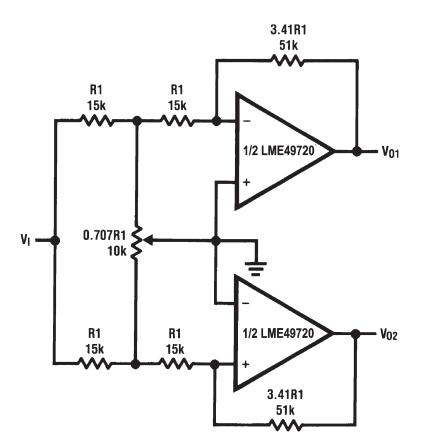


Figure 120. 2 Channel Panning Circuit (Pan Pot)

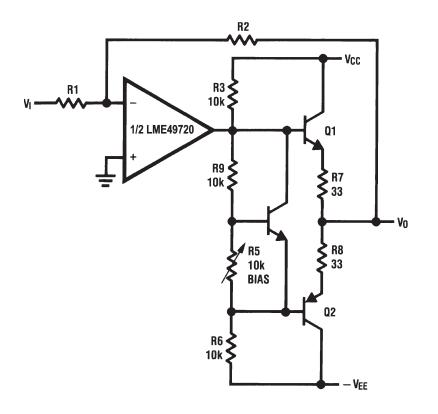
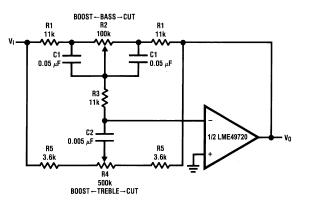


Figure 121. Line Driver



$$\begin{split} f_L &= \frac{1}{2\pi R2C1}, f_{LB} = \frac{1}{2\pi R1C1} \\ f_H &= \frac{1}{2\pi R5C2}, f_{HB} = \frac{1}{2\pi (R1 + R5 + 2R3)C2} \\ Illustration is: \\ f_L &= 32 \text{ Hz}, f_{LB} = 320 \text{ Hz} \\ f_H &= 11 \text{ kHz}, f_{HB} = 1.1 \text{ kHz} \end{split}$$





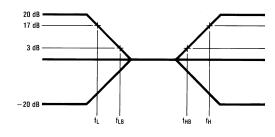
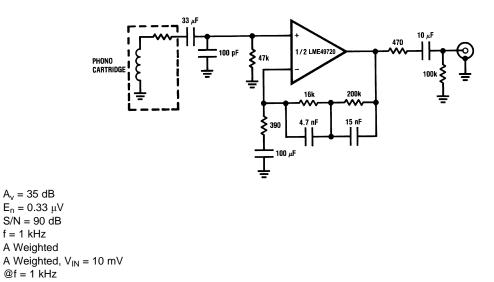
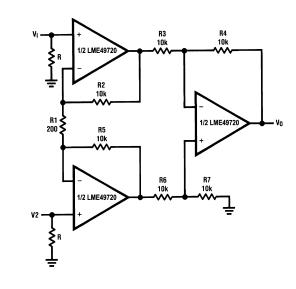


Figure 123. RIAA Preamp Behavior







 $\begin{array}{ll} \text{If } \text{R2} = \text{R5}, \text{R3} = \text{R6}, \text{R4} = \text{R7} \\ \text{V0} = \left(1 + \frac{2\text{R2}}{\text{R1}}\right) \frac{\text{R4}}{\text{R3}} (\text{V2} - \text{V1}) \\ \text{Illustration is:} \\ \text{V0} = 101 (\text{V2} - \text{V1}) \end{array}$





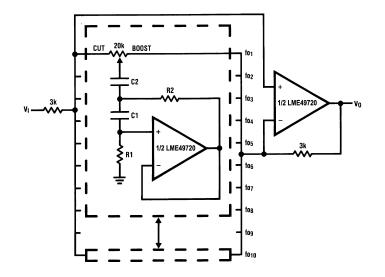


Figure 126. 10 Band Graphic Equalizer

Table 4. Typical Values for Band Gr	raphic Equalizer
-------------------------------------	------------------

fo (Hz)	C ₁	C ₂	R ₁	R ₂
32	0.12μF	4.7μF	75kΩ	500Ω
64	0.056µF	3.3μF	68kΩ	510Ω
125	0.033µF	1.5μF	62kΩ	510Ω
250	0.015μF	0.82µF	68kΩ	470Ω
500	8200pF	0.39µF	62kΩ	470Ω
1k	3900pF	0.22µF	68kΩ	470Ω
2k	2000pF	0.1µF	68kΩ	470Ω
4k	1100pF	0.056µF	62kΩ	470Ω
8k	510pF	0.022µF	68kΩ	510Ω
16k	330pF	0.012µF	51kΩ	510Ω



11 Power Supply Recommendations

The LME49720 is designed to operate a power supply from $\pm 2.5V$ to $\pm 17V$. Therefore, the output voltage range of the power supply must be within this range. The current capability of upper power must not exceed the maximum current limit of the power switch.

11.1 Power Supply Decoupling Capacitors

The LME49720 requires adequate power supply decoupling to ensure a low total harmonic distortion (THD). Place a low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1 μ F, within 2 mm of the V+ and V-pins. This choice of capacitor and placement helps with higher frequency transients, spikes, or digital hash on the line. In addition to the 0.1 μ F ceramic capacitor, it is recommended to place a 2.2 μ F to 10 μ F capacitor on the V+ and V- pins. This larger capacitor acts as a charge reservoir, providing energy faster than the board supply, thus helping to prevent any droop in the supply voltage.

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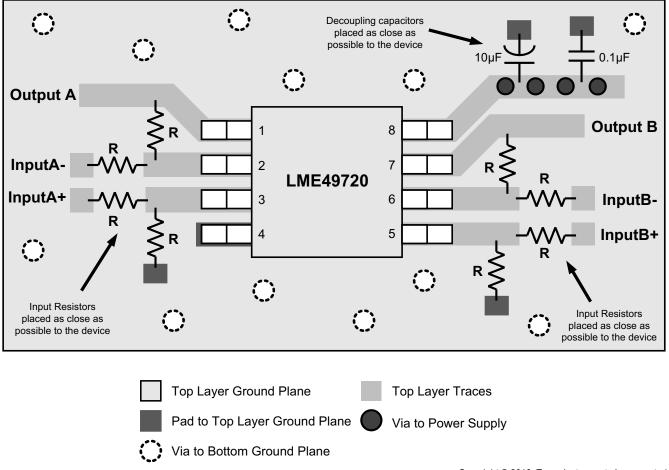
12 Layout

12.1 Layout Guidelines

12.1.1 Component Placement

Place all the external components close to the device. Placing the decoupling capacitors as close as possible to the device is important for low total harmonic distortion (THD). Any resistance or inductance in the trace between the device and the capacitor can cause a loss in efficiency.

12.2 Layout Example



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Figure 127. LME49720SOIC Layout Example





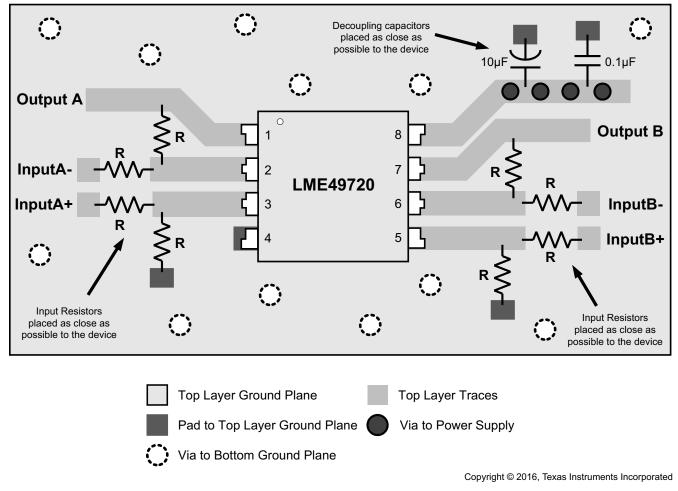


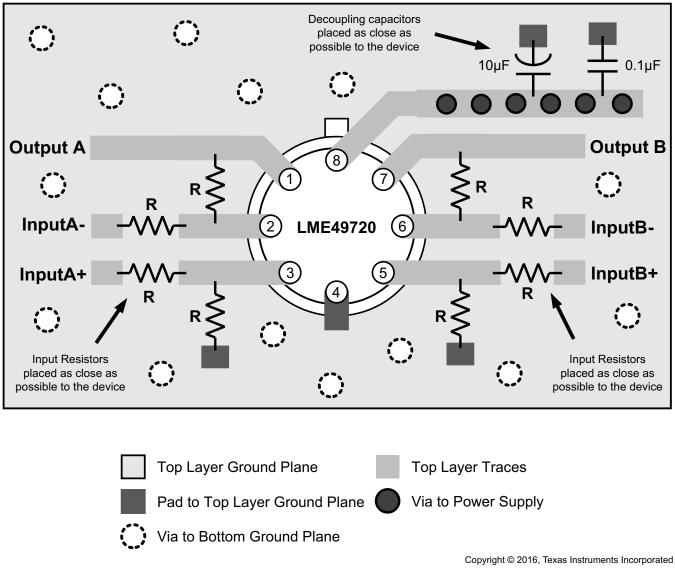
Figure 128. LME49720PDIP Layout Example

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Layout Example (continued)







13 Device and Documentation Support

13.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

13.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

13.3 Trademarks

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13.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

13.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



7-Nov-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	•	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
LME49720MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	L49720 MA	Samples
LME49720NA/NOPB	ACTIVE	PDIP	Р	8	40	Green (RoHS & no Sb/Br)	CU SN	Level-1-NA-UNLIM	-40 to 85	LME 49720NA	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

7-Nov-2017

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal	
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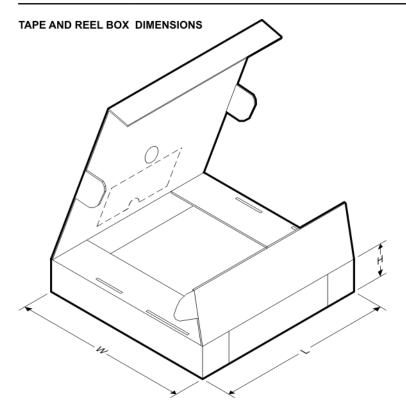
Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LME49720MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

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PACKAGE MATERIALS INFORMATION

4-May-2017



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LME49720MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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